

1. General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package. This "series ET" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers including microcontrollers. It is used in applications where "high junction operating temperature" capability is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- · Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with sensitive gate
- High junction operating temperature capability
- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only

3. Applications

- Applications subject to high temperature
- Electronic thermostats (heating and cooling)
- Motor controls e.g. washing machines and vacuum cleaners
- Refrigeration and air-conditioner compressor controls

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Tun | Max | Unit |
|---------------------|--|---|-----|-----|-------|------|
| Symbol | Farameter | Conditions | | Тур | IVIAX | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | - | 100 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 10 | A |





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| Symbol | Parameter | Conditions | I | Min | Тур | Мах | Unit |
|-----------------------|---------------------------------------|--|---|-----|-----|-----|------|
| Static charac | teristics | · · · · · · | I | | | _ | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | 0.5 | - | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | (| 0.5 | - | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | (| 0.5 | - | 10 | mA |
| Dynamic cha | racteristics | · · · · · | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | | 50 | - | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 1 V/µs; gate open circuit | : | 5 | - | - | A/ms |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | Τ2 | mounting base; main terminal 2 | TO-220AB (SOT78) | |

6. Ordering information

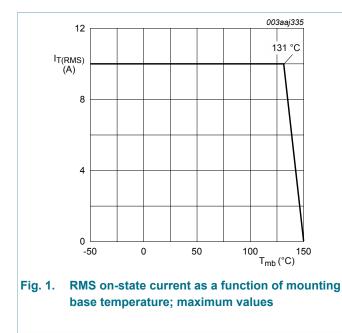
| Table 3. Ordering in | formation | | |
|----------------------|-----------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BTA410-800ET | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 |

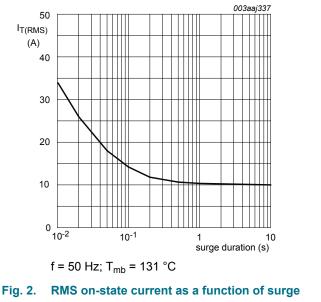
7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

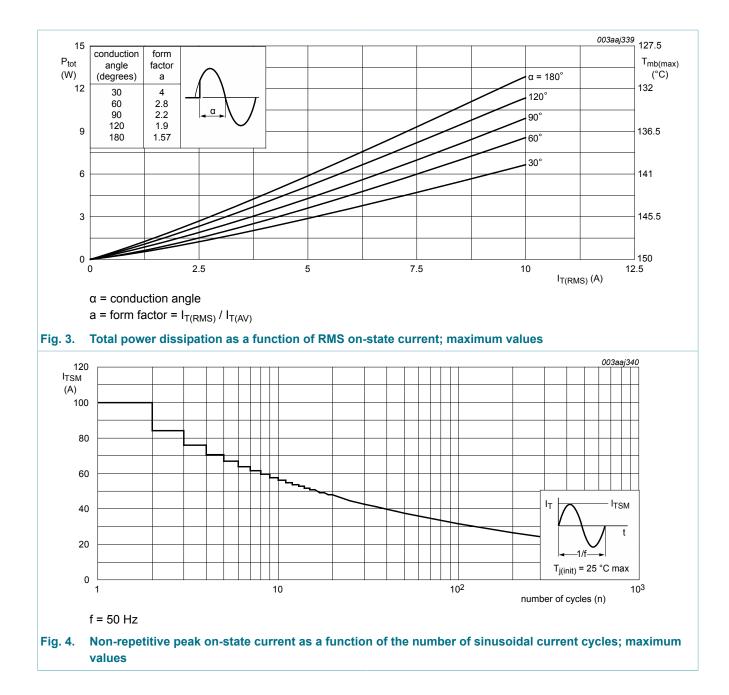
| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | 10 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; Fig. 4; Fig. 5$ | - | 100 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | 110 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 50 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |





duration; maximum values

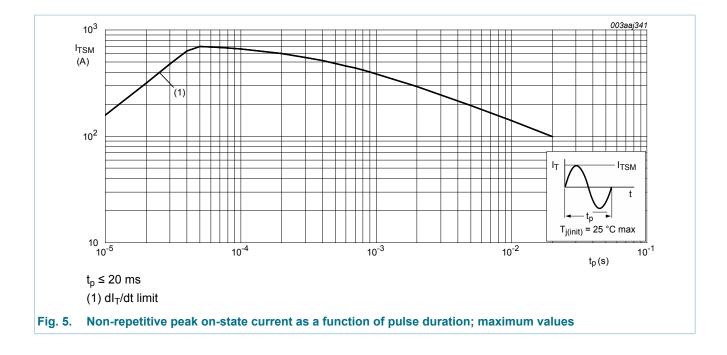
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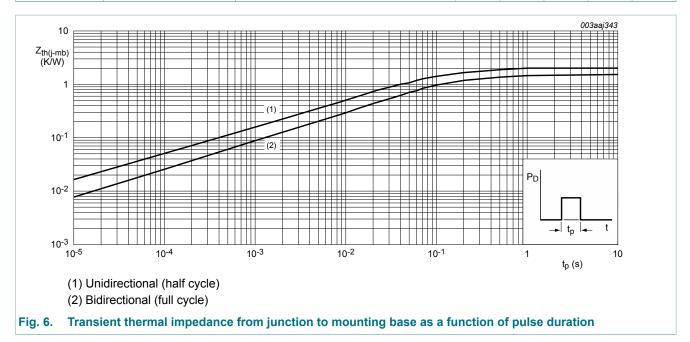
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8. Thermal characteristics

| Table 5. Th | nermal characteristics | | | | | |
|----------------------|---|---------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| ing mb) | thermal resistance | full cycle; Fig. 6 | - | - | 1.5 | K/W |
| | from junction to mounting base | half cycle; <u>Fig. 6</u> | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



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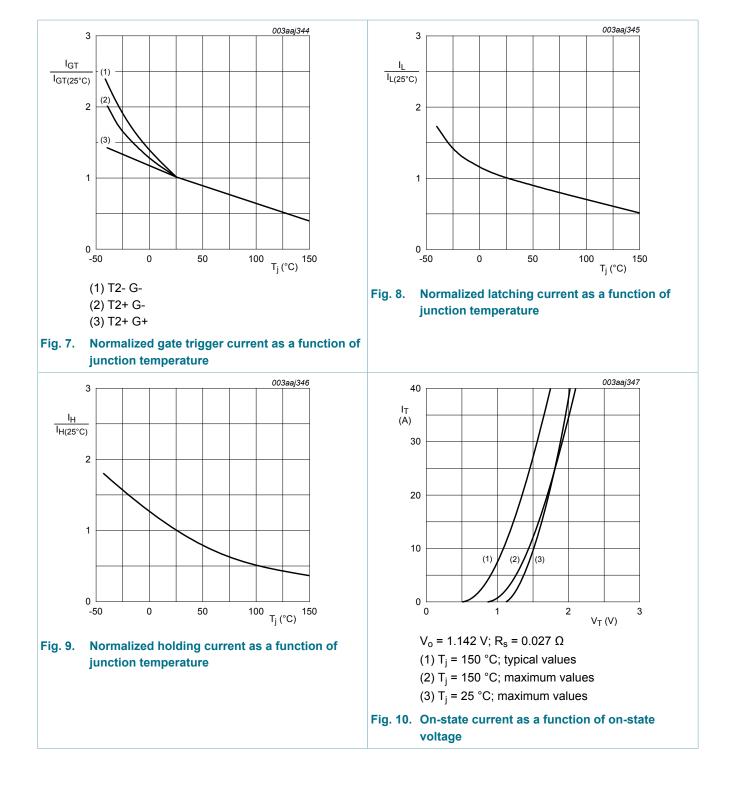
9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|------|-----|-----|------|
| Static chara | acteristics | | | | _ | |
| I _{GT} | gate trigger current | V_D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 0.5 | - | 10 | mA |
| | | V_D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | 0.5 | - | 10 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 0.5 | - | 10 | mA |
| IL latching current | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 25 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 30 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 25 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 15 | mA |
| V _T | on-state voltage | I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.6 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u> | - | 0.7 | 1 | V |
| | | V _D = 400 V; T _j = 150 °C; <u>Fig. 11</u> | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 150 °C | - | 0.4 | 2 | mA |
| Dynamic cl | naracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 50 | - | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 10 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit | 2 | - | - | A/ms |
| | | V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 10 V/µs; gate open circuit | 3.5 | - | - | A/ms |
| | | V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 1 V/µs; gate open circuit | 5 | - | - | A/ms |

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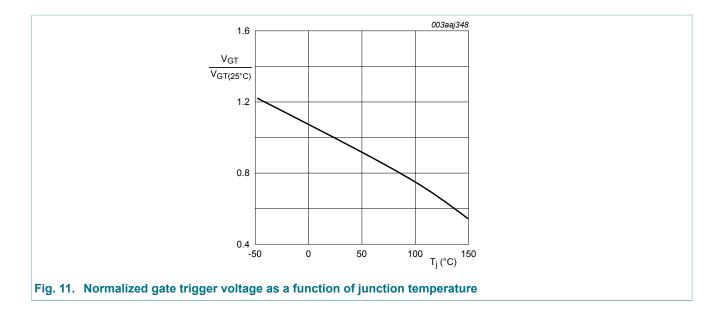
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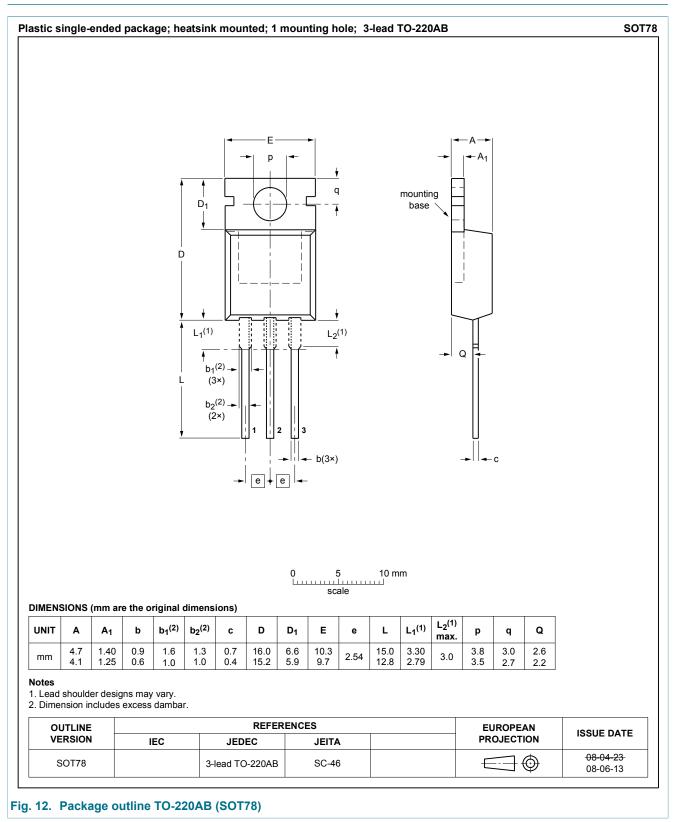
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10. Package outline



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|--------------------------------------|-------------------------------|---|
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[2] The term 'short data sheet' is explained in section "Definitions".

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